X-rays digital radiography in CMOS Tech (FCT)



X-ray chip structure in CMOS technology



CMOS digital dental X-rays microsystem



Lab-on-a-chip









LAB-ON-A-CHIP for uric acid



Microspectrometer for UV, visible and IV with digital output and bus interface



Chip-size antennas, RF CMOS 0.18 um









Glass (12x12mm²)





Chip-size antennas II







Alimentação



Peltier effect for cooling Applications



Peltier effect

A current flowing through the junction of two materials generates / removes thermal energy

7 Solid state cooling devices





Inside a Peltier device



TE^{*} Elements (Pellets) – Bismuth Telluride / Antimony Telluride



Good materiais for Peltier devices

- High Seebeek coefficient α (V/°C)
- Low electrical resistivity p (Ohm-m)
- Low thermal conductivity λ (Wm⁻¹K⁻¹)



 $ZT = \frac{\alpha}{\alpha \lambda} T$

n-type: Bi₂Te₃ – Bismuth telluride p-type: Sb₂Te₃ – Antimony telluride

Fabrication technique



- 2 crucibles (Bi/Sb and Te)
- Power controlled by PID
- Constant evaporating rate
- Two oscillating crystals
- Substrate heated
- Deposition very slow: 2 µm/h

Thermal co-evaporation



Seebeck effect Applications



Thermoelectric generators in space High reliability

Citizen Eco Drive Thermo Powered from body heat

Thermoelectric microsystem

